INTEGRATED CIRCUITS

DATA SHEET



TDA6502; TDA6502A; TDA6503; TDA6503A

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

Preliminary specification Supersedes data of 2000 Jan 24 File under Integrated Circuits, IC02 2000 Mar 16





TDA6502; TDA6502A; TDA6503; TDA6503A

CONTENT	rs	13	TEST AND APPLICATION INFORMATION
1 2	FEATURES APPLICATIONS	13.1 13.2 13.3	Test circuits Measurement circuit Tuning amplifier
3 3.1 3.2 4 5 6 7	GENERAL DESCRIPTION I ² C-bus format 3-wire bus format QUICK REFERENCE DATA ORDERING INFORMATION BLOCK DIAGRAM PINNING	13.4 13.5 13.5.1 13.5.2 13.6 13.6.1 13.6.2	Crystal oscillator Examples of I ² C-bus data format sequences for TDA6502 and TDA6503 Write sequences to register C2 Read sequences from register C3 Examples of 3-wire bus data format sequences for TDA6502 and TDA6503 18-bit sequence 19-bit sequence
8 8.1 8.2 8.2.1 8.2.2 8.2.3 8.2.4	FUNCTIONAL DESCRIPTION Control mode selection I ² C-bus data format I ² C-bus address selection Write mode Read mode Power-on reset	13.6.3 14 15 16 16.1	27-bit sequence INTERNAL PIN CONFIGURATION PACKAGE OUTLINE SOLDERING Introduction to soldering surface mount packages
8.3 8.3.1 9	3-wire bus data format Power-on reset LIMITING VALUES	16.2 16.3 16.4	Reflow soldering Wave soldering Manual soldering
10 11 12	THERMAL CHARACTERISTICS CHARACTERISTICS TIMING CHARACTERISTICS	17 18 19	DEFINITIONS LIFE SUPPORT APPLICATIONS PURCHASE OF PHILIPS I ² C COMPONENTS

TDA6502; TDA6502A; TDA6503A

1 FEATURES

- Single-chip 5 V mixer/oscillator and synthesizer for cable TV and VCR tuners
- Pin-to-pin compatible with TDA6402, TDA6402A, TDA6403 and TDA6403A
- Universal bus protocol (I²C-bus or 3-wire bus)
 - Bus protocol for 18 or 19-bit transmission (3-wire bus)
 - Extra protocol for 27-bit transmission (test modes and features for 3-wire bus)
 - Address + 4 data bytes transmission (I²C-bus 'write' mode)
 - Address + 1 status byte (I²C-bus 'read' mode)
 - 4 independent I²C-bus addresses.
- 1 PMOS buffer for UHF band selection (25 mA)
- 3 PMOS buffers for general purpose, e.g. 2 VHF sub-bands, FM sound trap (25 mA)
- 33 V tuning voltage output
- · In-lock detector
- 5-step analog-to-digital converter (3 bits in I²C-bus mode)
- 15-bit programmable divider
- Programmable reference divider ratio (64, 80 or 128)
- Programmable charge pump current (60 or 280 μA)
- · Varicap drive disable
- Balanced mixer with a common emitter input for VHF (single input)
- Balanced mixer with a common base input for UHF (balanced input)
- · 2-pin common emitter oscillator for VHF
- 4-pin common emitter oscillator for UHF
- IF preamplifier with asymmetrical 75 Ω output impedance able to drive loads from 75 Ω upwards
- · Low power
- Low radiation
- · Small size
- The TDA6502A and TDA6503A differ from the TDA6502 and TDA6503 by the UHF port protocol in the I²C-bus mode (see Tables 3 and 4).



2 APPLICATIONS

 Cable tuners for TV and VCR (switched concept for VHF).

3 GENERAL DESCRIPTION

The TDA6502, TDA6502A, TDA6503 and TDA6503A are programmable 2-band mixers/oscillators and synthesizers intended for VHF/UHF TV and VCR tuners (see Fig.1).

Partitioning of the bands is the responsibility of the customer providing VHF is below 500 MHz and UHF is below 900 MHz.

The devices include two double balanced mixers and two oscillators for the VHF and UHF band respectively, an IF amplifier and a PLL synthesizer. The VHF band can be split-up into two sub-bands using a proper oscillator application and a switchable inductor.

Two pins are available between the mixer output and the IF amplifier input to enable IF filtering for improved signal handling.

The port register provides four PMOS ports. Band selection is provided by port register UHF. When port register UHF is 'on', the UHF mixer-oscillator is active and the VHF band is switched off. When port register UHF is 'off', the VHF mixer-oscillator is active and the UHF band is off. Port registers VHFL and VHFH are used to select the VHF sub-bands. Port register FMST is a general purpose port, that can be used to switch an FM sound trap. When the ports are used, the sum of the drain currents has to be limited to 30 mA.

The synthesizer consists of a 15-bit programmable divider, a crystal oscillator and its programmable reference divider and a phase comparator (phase/frequency detector) combined with a charge pump which drives the tuning amplifier, including the 33 V output at pin VT. Depending on the reference divider ratio (64, 80 or 128), the phase comparator operates at 62.5, 50 or 31.25 kHz with a 4 MHz crystal.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503;

Depending on the voltage applied to pin SW (see Table 2) the device is operating in the I²C-bus mode or 3-wire bus mode.

In the 3-wire bus mode, pin LOCK/ADC is the 'lock' output of the PLL and is at LOW level when the PLL is locked. Lock detector bit FL of the status byte is set to logic 1 when the loop is locked and is read on the SDA line during a READ operation in I²C-bus mode only.

In the I²C-bus mode only, pin LOCK/ADC is the ADC input for digital AFC control. The ADC code is read during a READ operation on the I²C-bus.

In the test mode, in both I²C-bus mode and 3-wire bus mode, pin LOCK/ADC is used as a test output for f_{REF} and $\frac{1}{2}f_{DIV}$.

3.1 I2C-bus format

Five serial bytes (including the address byte) are required to address the device, select the VCO frequency, program the four ports, set the charge pump current and set the reference divider ratio. The device has four independent I²C-bus addresses which can be selected by applying a specific voltage to pin CE/AS.

3.2 3-wire bus format

Data is transmitted to the device during a HIGH level on pin CE/AS (enable line). The device is accessible with 18-bit and 19-bit data formats (see Figs 4 and 5). The first four bits are used to program the PMOS ports and the remaining bits control the programmable divider. A 27-bit data format (see Fig.6) may also be used to set the charge pump current, the reference divider ratio and the test modes.

It is not allowed to address the device with words whose length is different from 18, 19 or 27 bits.

Table 1 Data word length for 3-wire bus format

DATA WORD	REFERENCE DIVIDER ⁽¹⁾	FREQUENCY STEP
18-bit	64	62.50 kHz
19-bit	128	31.25 kHz
27-bit	programmable	programmable

Note

 The selection of the reference divider is given by an automatic identification of the data word length. When the 27-bit format is used, the reference divider is controlled by bits RSA and RSB (see Table 8). More details are given in Section 8.3.

TDA6502; TDA6502A; TDA6503A

4 QUICK REFERENCE DATA

Measured over full voltage and temperature ranges.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CC}	supply voltage	operating	4.5	5	5.5	V
I _{CC}	supply current	all PMOS ports are off; V _{CC} = 5V	_	71	-	mA
f _{XTAL}	crystal oscillator frequency		_	4.0	_	MHz
I _{o(PMOS)}	PMOS port output current	note 1	_	_	30	mA
P _{tot}	total power dissipation	note 2	_	_	520	mW
T _{stg}	IC storage temperature		-40	_	+150	°C
T _{amb}	ambient temperature		-20	_	+85	°C
f _{RF}	RF frequency	VHF band	40	_	800	MHz
		UHF band	200	_	900	MHz
G _V	voltage gain	VHF band	_	20	_	dB
		UHF band	_	32	_	dB
NF	noise figure	VHF band	_	7.5	_	dB
		UHF band	_	7	_	dB
Vo	output voltage (causing 1% cross	VHF band	_	110	_	dΒμV
	modulation in channel)	UHF band	_	110	_	dBμV

Notes

- 1. One buffer 'on', $I_0 = 25$ mA; two buffers 'on', maximum sum of $I_0 = 30$ mA.
- 2. The power dissipation is calculated as follows:

$$\label{eq:Ptot} P_{tot} \ = \ V_{CC} \times \left(I_{CC} - I_o \right) + V_{P(sat)} \times I_o + \frac{\left(0.5 \times 33 V \right)^2}{22 \ k\Omega}$$

where

 $V_{P(sat)}$ = output saturation voltage on the buffer output

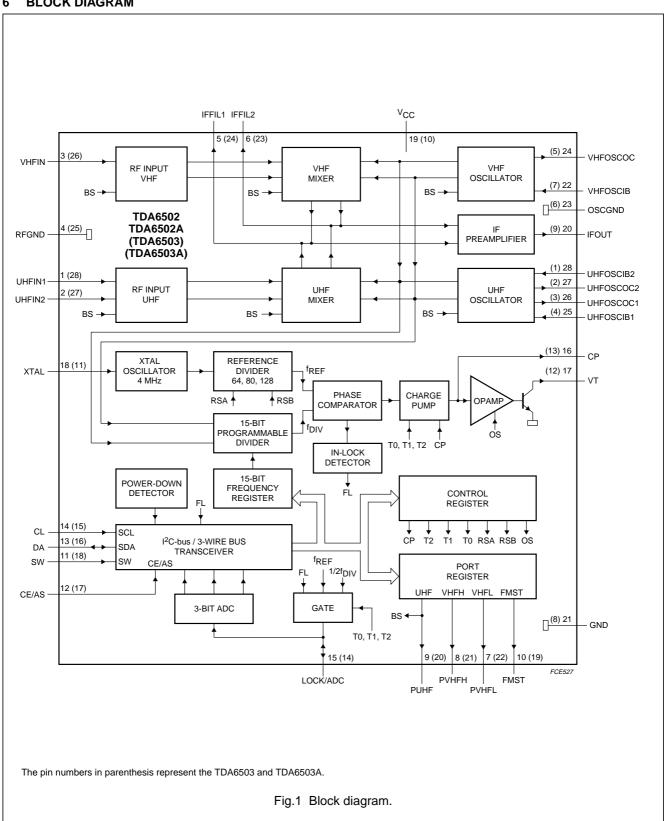
I_o = source current for one buffer output.

5 ORDERING INFORMATION

TYPE		PACKAGE					
NUMBER	NAME	DESCRIPTION	VERSION				
TDA6502; TDA6502A; TDA6503; TDA6503A	SSOP28	plastic shrink small outline package; 28 leads; body width 5.3 mm	SOT341-1				

TDA6502; TDA6502A; TDA6503; TDA6503A

BLOCK DIAGRAM



2000 Mar 16 6

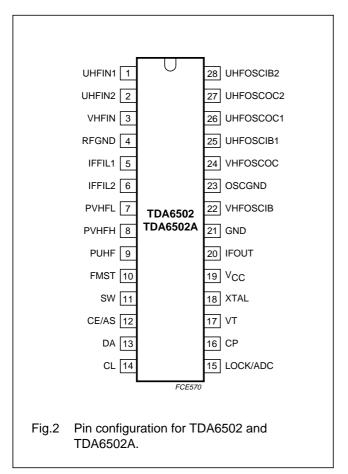
TDA6502; TDA6502A; TDA6503; TDA6503A

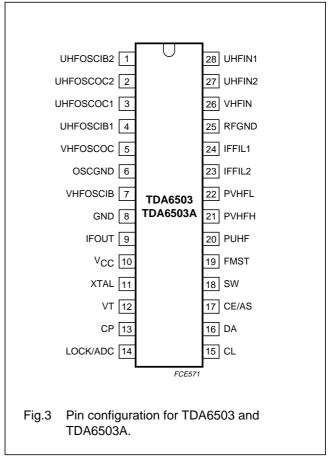
7 PINNING

	PIN			
SYMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	DESCRIPTION	
UHFIN1	1	28	UHF RF input 1	
UHFIN2	2	27	UHF RF input 2	
VHFIN	3	26	VHF RF input	
RFGND	4	25	RF ground	
IFFIL1	5	24	IF filter output 1	
IFFIL2	6	23	IF filter output 2	
PVHFL	7	22	PMOS port output, general purpose (e.g. VHF low sub-band)	
PVHFH	8	21	PMOS port output, general purpose (e.g. VHF high sub-band)	
PUHF	9	20	PMOS port output, UHF band	
FMST	10	19	PMOS port output, general purpose (e.g. FM sound trap)	
SW	11	18	bus format selection input: I ² C-bus mode or 3-wire bus mode	
CE/AS	12	17	chip enable input in 3-wire bus mode or address selection input in I ² C-bus mode	
DA	13	16	serial data input/output	
CL	14	15	serial clock input	
LOCK/ADC	15	14	lock detector output in 3-wire bus mode or ADC input in I ² C-bus mode	
СР	16	13	charge pump output	
VT	17	12	tuning voltage output	
XTAL	18	11	crystal oscillator input	
V _{CC}	19	10	supply voltage	
IFOUT	20	9	IF output	
GND	21	8	digital ground	
VHFOSCIB	22	7	VHF oscillator input base	
OSCGND	23	6	oscillator ground	
VHFOSCOC	24	5	VHF oscillator output collector	
UHFOSCIB1	25	4	UHF oscillator input 1 (base)	
UHFOSCOC1	26	3	UHF oscillator output 1 (collector)	
UHFOSCOC2	27	2	UHF oscillator output 2 (collector)	
UHFOSCIB2	28	1	UHF oscillator input 2 (base)	

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A





8 FUNCTIONAL DESCRIPTION

8.1 Control mode selection

The device is controlled via the I²C-bus or the 3-wire bus, depending on the voltage applied to pin SW (see Table 2).

A LOW level on pin SW enables the I²C-bus: pins CE/AS, DA and CL are used as address selection (AS), serial data (SDA) and serial clock (SCL) input respectively.

A HIGH level on pin SW enables the 3-wire bus: pins CE/AS, DA and CL are used as chip enable (CE), data and clock inputs respectively.

Table 2 Bus format selection

PIN						
SYMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	I ² C-BUS MODE	3-WIRE BUS MODE		
SW	11	18	LOW-level voltage or ground	HIGH-level voltage or open-circuit		
CE/AS	12	17	address selection input	enable input		
DA	13	16	serial data input	data input		
CL	14	15	serial clock input	clock input		
LOCK/ADC	15	14	ADC input or test output	lock detector output or test output		

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503

8.2 I²C-bus data format

8.2.1 I²C-BUS ADDRESS SELECTION

The module address contains programmable address bits MA1 and MA0 (see Tables 3, 4 and 9) which offer the possibility of having several synthesizers (up to 4) in one system by applying a specific voltage on pin CE/AS. The relationship between bits MA1 and MA0 and the input voltage applied to pin CE/AS is given in Table 6.

8.2.2 WRITE MODE

The write mode is defined by the address byte ADB with bit $R/\overline{W} = 0$ (see Tables 3 and 4).

Data bytes can be sent to the device after the address transmission (first byte). Four data bytes are needed to fully program the device.

The bus transceiver has an auto-increment facility which permits the programming of the device within one single transmission (address byte + 4 data bytes). The device can also be partially programmed providing that the first data byte following the address byte is divider byte DB1 or the control byte CB.

The first bit of byte DB1 indicates whether frequency data (first bit = 0) or control and band-switch data (first bit = 1) will follow. Until an I^2C -bus STOP command is sent by the controller, additional data bytes can be entered without the need to re-address the device.

The frequency register is loaded after the 8th clock pulse of byte DB2, the control register is loaded after the 8th clock pulse of the byte CB and the band-switch register is loaded after the 8th clock pulse of byte BB.

Table 3 I²C-bus data format for write mode of TDA6502 and TDA6503

NAME	ВҮТЕ				Bľ	тѕ			
NAME	BILE	MSB							LSB
Address byte	ADB	1	1	0	0	0	MA1	MA0	$R/\overline{W} = 0$
Divider byte 1	DB1	0	N14	N13	N12	N11	N10	N9	N8
Divider byte 2	DB2	N7	N6	N5	N4	N3	N2	N1	N0
Control byte	СВ	1	СР	T2	T1	T0	RSA	RSB	OS
Band-switch byte	BB	Х	Х	Х	Х	FMST	PUHF	PVHFH	PVHFL

Table 4 12C-bus data format for write mode of TDA6502A and TDA6503A

NAME	ВҮТЕ				В	IT			
NAIVIE	BILE	MSB							LSB
Address byte	ADB	1	1	0	0	0	MA1	MA0	$R/\overline{W} = 0$
Divider byte 1	DB1	0	N14	N13	N12	N11	N10	N9	N8
Divider byte 2	DB2	N7	N6	N5	N4	N3	N2	N1	N0
Control byte	СВ	1	СР	T2	T1	T0	RSA	RSB	os
Band-switch byte	BB	Х	Х	Х	Х	PUHF	FMST	PVHFH	PVHFL

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A

Table 5 Description of the bits used in Tables 3 and 4

BIT	DESCRIPTION
MA1 and MA0	programmable address bits (see Table 6)
R/W	logic 0 for write mode
N14 to N0	programmable divider bits: $N = N14 \times 2^{14} + N13 \times 2^{13} + + N1 \times 2^1 + N0$
СР	charge pump current control bit:
	logic 0: charge pump current is 60 μA
	logic 1: charge pump current is 280 μA (default)
T2, T1 and T0	test bits (see Table 7)
RSA and RSB	reference divider ratio select bits (see Table 8)
OS	tuning amplifier control bit:
	logic 0: tuning voltage is 'on' (during normal operating)
	logic 1: tuning voltage is 'off'; high-impedance output of pin VT (default)
PVHFL, PVHFH, PUHF and FMST	PMOS ports control bits:
	logic 0: corresponding buffer is 'off' (default)
	logic 1: corresponding buffer is 'on'
X	don't care

Table 6 Address selection bits (I²C-bus mode)

MA1	MA0	VOLTAGE APPLIED TO PIN CE/AS			
0	0	0 V to 0.1V _{CC}			
0	1	0.2V _{CC} to 0.3V _{CC} or open-circuit			
1	0	0.4V _{CC} to 0.6V _{CC}			
1	1	0.9V _{CC} to 1.0V _{CC}			

Table 7 Test mode bits

T2	T1	T0	TEST MODE
0	0	0	normal mode
0	0	1	normal mode (note 1)
0	1	Х	charge pump is off
1	1	0	charge pump is sinking current
1	1	1	charge pump is sourcing current
1	0	0	f _{REF} is available on pin LOCK/ADC (note 2)
1	0	1	½f _{DIV} is available on pin LOCK/ADC (note 2)

Notes

- 1. This is the default mode at Power-on reset.
- 2. The ADC input cannot be used when these test modes are active; see Section 8.2.3 for more information.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503;

Table 8 Reference divider ratio select bits

RSA	RSB	REFERENCE DIVIDER RATIO	FREQUENCY STEP (kHz)
Х	0	80	50
0	1	128	31.25
1	1	64	62.5

8.2.3 READ MODE

The read mode is defined by the address byte ADB with bit $R/\overline{W} = 1$ (see Table 9).

After the slave address has been recognized, the device generates an acknowledge pulse and status byte SB is transferred on the SDA line (MSB first). Data is valid on the SDA line during a HIGH level of the SCL line. A second data byte can be read from the device if the microcontroller generates an acknowledge on the SDA line (master acknowledge).

End of transmission will occur if no master acknowledge occurs. The device will then release the data line to allow the microcontroller to generate a STOP condition.

Bit POR is set to logic 1 at power-on. The bit is reset when an end-of-data is detected by the device (end of a read sequence). Control of the loop is made possible with bit FL which indicates when the loop is locked (bit FL = 1)

A built-in ADC input is available on pin LOCK/ADC (I²C-bus mode only). This converter can be used to apply AFC information to the microcontroller of the IF section of the television.

Table 9 Read data format

NAME	BYTE				В	IT			
NAME	BIIL	MSB ⁽¹⁾							LSB
Address byte	ADB	1	1	0	0	0	MA1	MA0	$R/\overline{W} = 1$
Status byte	SB	POR	FL	R	1	1	A2	A1	A0

Note

1. MSB is transmitted first.

Table 10 Description of the bits used in Table 9

BIT	DESCRIPTION
MA1 and MA0	programmable address bits (see Table 6)
R/W	logic 1 for read mode
POR	Power-on reset flag:
	logic 0: at power-off
	logic 1: at power-on
FL	in-lock flag:
	logic 0: loop is not locked
	logic 1: loop is locked
R	ready flag:
	logic 0: mode after Power-on reset (bit T2 = 0, bit T1 = 0 and bit T0 = 1) and the PLL is locked
	logic 1: in other conditions
A2, A1 and A0	digital outputs of the 5-level ADC (see Table 11)

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503;

Table 11 Digital outputs for analog input levels (note 1)

A2	A1	Α0	VOLTAGE APPLIED TO PIN LOCK/ADC
0	0	0	0 to 0.15V _{CC}
0	0	1	0.15V _{CC} to 0.30V _{CC}
0	1	0	0.30V _{CC} to 0.45V _{CC}
0	1	1	0.45V _{CC} to 0.60V _{CC}
1	0	0	0.60V _{CC} to 1.00V _{CC}

Note

1. Accuracy is $\pm 0.03 \times V_{CC}$.

8.2.4 POWER-ON RESET

The power-on detection threshold voltage V_{POR} is set to 3.2 V at room temperature. Below this threshold the device is reset to the power-on state.

At power-on state the following actions take place:

- The charge pump current is set to 280 μA
- The tuning voltage output is disabled
- The test bits T2, T1 and T0 are set to logic '001'
- The divider bit RSB is set to logic 1
- Port register UHF is 'off', which means that the UHF oscillator and the UHF mixer are switched off. Consequently, the
 VHF oscillator and the VHF mixer are switched on. Port registers VHFL and VHFH are 'off', which means that the VHF
 tank circuit is operating in the VHF low sub-band. The tuning amplifier is switched off until the first transmission. In that
 case, the tank circuit is supplied with the maximum tuning voltage. The oscillator is therefore operating at the end of
 the VHF low sub-band.

Table 12 Default setting of the bits at Power-on reset

NAME	BYTE				BI	TS			
NAME	DIIE	MSB							LSB
Address byte	ADB	1	1	0	0	0	MA1	MA0	Х
Divider byte 1	DB1	0	Х	Х	Х	Х	Х	Х	Х
Divider byte 2	DB2	Х	Х	Х	Х	Х	Х	Х	Х
Control byte	СВ	1	1	0	0	1	Х	1	1
Band switch byte	BB	Х	Х	Х	Х	0	0	0	0

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503A

8.3 3-wire bus data format

During a HIGH level on pin CE/AS (enable line), the data is clocked into the data register at the HIGH-to-LOW transition of the clock (see Figs 4 and 5).

The first four bits control the PMOS ports and are loaded into the internal band-switch register on the 5th rising edge of the clock pulse.

The frequency bits are loaded into the frequency register at the HIGH-to-LOW transition of the enable line when an 18-bit or 19-bit data word is transmitted. When a 27-bit data word is transmitted, the frequency bits are loaded into the frequency register on the 20th rising edge of the clock pulse and the control bits at the HIGH-to-LOW transition of the enable line (see Fig.6).

In this control mode the reference divider is given by bits RSA and RSB (see Table 8).

The test bits T2, T1 and T0, the charge pump bit CP, the ratio select bit RSB and bit OS can only be selected or changed with a 27-bit transmission. They remain programmed if an 18-bit or 19-bit transmission occurs. Only bit RSA is controlled by the transmission length when the 18-bit or 19-bit format is used. When an 18-bit data word is transmitted, the most significant bit of the divider (bit N14) is internally set to logic 0 and bit RSA is set to logic 1. When a 19-bit data word is transmitted, bit RSA is set to logic 0.

It is not allowed to address the devices with words whose length is different from 18, 19 or 27 bits. A data word of less than 18 bits will not affect the frequency register of the device.

The definition of the bits is unchanged compared to the I^2C -bus mode.

8.3.1 POWER-ON RESET

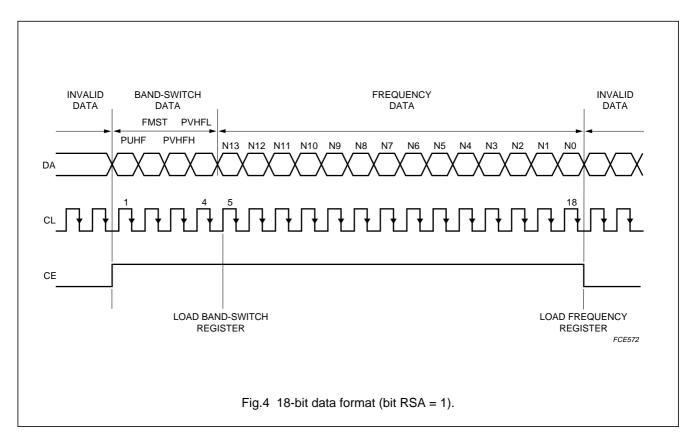
The power-on detection threshold voltage V_{POR} is set to 3.2 V at room temperature. Below this threshold the device is reset to the power-on state.

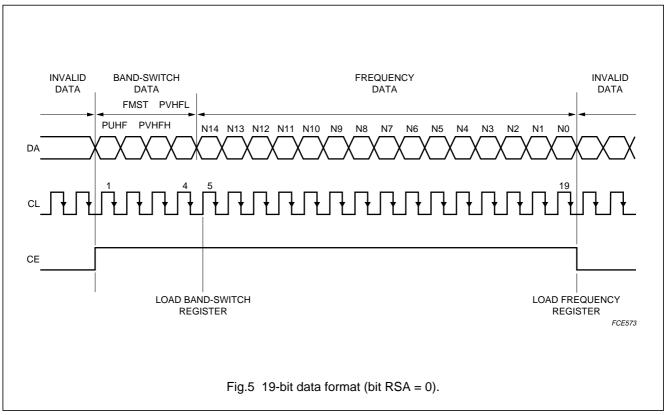
At power-on state the following actions take place:

- The charge pump current is set to 280 μA
- The test bits T2, T1 and T0 are set to logic '001'
- The divider bit RSB is set to logic 1
- · The tuning voltage output is disabled
- The tuning amplifier control bit OS is automatically reset to logic 0 in 18-bit and 19-bit modes when the first data word is received to allow normal operation
- Port register UHF is 'off', which means that the UHF oscillator and the UHF mixer are switched off.
 Consequently, the VHF oscillator and the VHF mixer are switched on. Port registers VHFL and VHFH are 'off', which means that the VHF tank circuit is operating in the VHF low sub-band. The tuning amplifier is switched off until the first transmission. In that case, the tank circuit is supplied with the maximum tuning voltage.
 The oscillator is therefore operating at the end of the VHF low sub-band
- The reference divider ratio is set to 64 or 128 if the first sequence to the device has 18 bits or 19 bits; if the sequence has 27 bits, the reference divider ratio is set by bits RSA and RSB (see Table 8).

2000 Mar 16

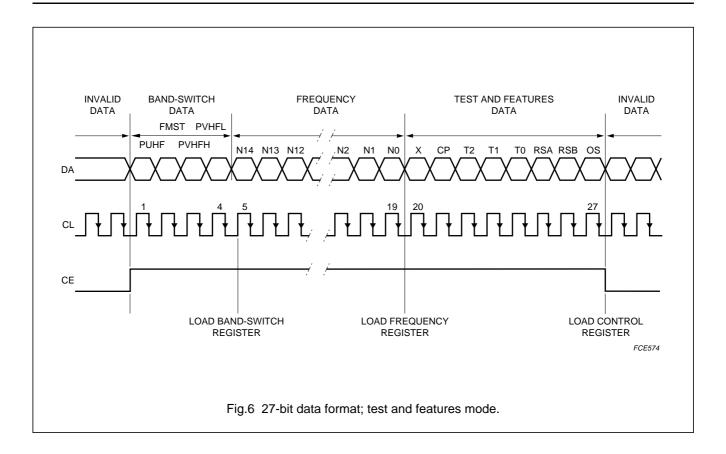
TDA6502; TDA6502A; TDA6503; TDA6503





5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503



5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A

9 LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); note 1.

	P	IN				
SYMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	PARAMETER	MIN.	MAX.	UNIT
V _{CC}	19	10	DC supply voltage	-0.3	+6	V
			OVS pulse time is 1 s; maximum current is 1 A	_	8	V
V _{Pn}	7 to 10	19 to 22	PMOS port output voltage	-0.3	V _{CC} +0.3	V
I _{Pn}	7 to 10	19 to 22	PMOS port output current	-1	+30	mA
V _{CP}	16	13	charge pump output voltage	-0.3	V _{CC} +0.3	V
V _{SW}	11	18	bus format selection input voltage	-0.3	V _{CC} + 0.3	V
V _{VT}	17	12	tuning voltage output	-0.3	+35	V
V _{LOCK/ADC}	15	14	lock/ADC output/input voltage	-0.3	V _{CC} +0.3	V
V_{CL}	14	15	serial clock input voltage	-0.3	+6	V
V_{DA}	13	16	serial data input/output voltage	-0.3	+6	V
I _{DA}	13	16	data output current (I ² C-bus mode)	-1	+10	mA
V _{CE/AS}	12	17	chip enable/address selection input voltage	-0.3	+6	V
V _{XTAL}	18	11	crystal input voltage	-0.3	V _{CC} +0.3	V
I _{O(n)}	1 to 6, 19 to 28	1 to 10, 23 to 28	output current of each pin to ground	_	-10	mA
t _{sc(max)}	_	_	maximum short-circuit time (all pins to V _{CC} and all pins to GND, OSCGND and RFGND)	_	10	s
T _{stg}	_	_	storage temperature	-40	+150	°C
T _{amb}	_	_	ambient temperature	-20	+85	°C
Tj	_	_	junction temperature	_	150	°C

Note

10 THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	TYP.	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	110	K/W

^{1.} Maximum ratings can not be exceeded, not even momentarily without causing irreversible IC damage. Maximum ratings can not be accumulated.

TDA6502; TDA6502A; TDA6503; TDA6503A

11 CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply; T _{an}	_{nb} = 25 °C					•
V _{CC}	supply voltage		4.5	5.0	5.5	V
I _{CC}	supply current	at V _{CC} = 5 V				
		all PMOS ports 'off'	_	71	78	mA
		one PMOS port 'on' and sourcing 25 mA	_	103	113	mA
		one PMOS port 'on' and sourcing 25 mA; a second port 'on' and sourcing 5 mA	_	111	122	mA
PLL part; V	$CC = 4.5 \text{ to } 5.5 \text{ V}; T_{amb} = -20 \text{ t}$	o +85 °C; unless otherwise specifie	ed			
FUNCTIONAL	RANGE					
V_{POR}	power-on reset supply voltage	below this supply voltage power-on reset becomes active	_	3.2	_	V
N	divider ratio	15-bit frequency word	64	_	32767	
		14-bit frequency word	64	_	16383	
f _{XTAL}	crystal oscillator frequency	$R_{XTAL} = 25 \text{ to } 300 \Omega$	_	4.0	_	MHz
Z _{XTAL}	input impedance (absolute value)	$f_{XTAL} = 4 \text{ MHz}$	600	1200	-	Ω
PMOS PORT	S: PINS PUHF, PVHFL, PVHFH	AND FMST				
I _{Pn(off)}	leakage current	V _{CC} = 5.5 V; V _{Pn} = 0 V	-10	_	_	μА
V _{Pn(sat)}	output saturation voltage	V _{Pn(sat)} = V _{CC} - V _{Pn} ; one buffer output is 'on' and sourcing 25 mA	_	0.25	0.4	V
LOCK OUTPU	T: PIN LOCK/ADC (IN 3-WIRE BL	JS MODE)			· ·	
I _{UNLOCK}	output current when the PLL is out-of-lock	V _{CC} = 5.5 V; V _O = 5.5 V	_	-	200	μΑ
V _{UNLOCK}	output saturation voltage when the PLL is out-of-lock	$V_{UNLOCK} = V_{CC} - V_O; I_O = 200 \mu A$	_	0.4	0.8	V
V _{LOCK}	output voltage	the PLL is locked	_	0.2	0.40	V
ADC INPUT:	PIN LOCK/ADC (IN I ² C-BUS MOI	DE)		•		
V _{ADC}	ADC input voltage	see Table 11	0	_	V _{CC}	V
I _{ADC(H)}	HIGH-level input current	$V_{ADC} = V_{CC}$	-	1-	10	μА
I _{ADC(L)}	LOW-level input current	V _{ADC} = 0 V	-10	_	_	μΑ
Bus format	SELECTION: PIN SW					
V _{SW(L)}	LOW-level input voltage		0	_	1.5	V
V _{SW(H)}	HIGH-level input voltage		3	_	V _{CC}	V
I _{SW(H)}	HIGH-level input current	$V_{SW} = V_{CC}$	_	_	10	μА
I _{SW(L)}	LOW-level input current	V _{SW} = 0 V	-100	_	_	μΑ

TDA6502; TDA6502A; TDA6503; TDA6503A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CHIP ENABLE	/ADDRESS SELECTION INPUT: PIN	CE/AS		1		
V _{CE/AS(L)}	LOW-level input voltage		0	_	1.5	V
V _{CE/AS(H)}	HIGH-level input voltage		3	_	5.5	V
I _{CE/AS(H)}	HIGH-level input current	V _{CE/AS} = 5.5 V	_	_	10	μΑ
I _{CE/AS(L)}	LOW-level input current	V _{CE/AS} = 0 V	-10	_	-	μΑ
	DATA INPUTS: PINS CL AND DA					•
V _{CL(L)} , V _{DA(L)}	LOW-level input voltage		0	_	1.5	V
V _{CL(H)} , V _{DA(H)}	HIGH-level input voltage		3	-	5.5	V
I _{CL(H)} , I _{DA(H)}	HIGH-level input current	V _{BUS} = 5.5 V; V _{CC} = 0 V	_	-	10	μΑ
		V _{BUS} = 5.5 V; V _{CC} = 5.5 V	_	_	10	μΑ
I _{CL(L)} , I _{DA(L)}	LOW-level input current	V _{BUS} = 1.5 V; V _{CC} = 0 V	_	_	10	μΑ
		V _{BUS} = 0 V; V _{CC} = 5.5 V	-10	_	_	μΑ
Dата оитрит	T: PIN DA (IN I ² C-BUS MODE ONL)	·)				
I _{DA(H)}	HIGH-level output current	V _{DA} = 5.5 V	_	_	10	μΑ
V _{DA(H)}	HIGH-level output voltage	I _{DA} = 3 mA (sink current)	_	_	0.4	V
CLOCK FREQ	UENCY (I ² C-BUS MODE)					•
f _{clk}	clock frequency		_	_	400	kHz
CHARGE PUM	IP OUTPUT: PIN CP		•		•	
I _{CP(H)}	HIGH-level input current (absolute value)	CP = 1	_	280	_	μΑ
I _{CP(L)}	LOW-level input current (absolute value)	CP = 0	_	60	-	μΑ
I _{CP(leak)}	off-state leakage current	T2 = 0; T1 = 1	-15	-0.5	+15	nA
TUNING VOLT	AGE OUTPUT: PIN VT					
I _{VT(off)}	leakage current when switched-off	OS = 1; tuning supply is 33 V	_	-	10	μΑ
V_{VT}	output voltage when the loop is closed	OS = 0; T2 = 0; T1 = 0; T0 = 1; $R_L = 27 \text{ k}\Omega$; tuning supply is 33 V	0.2	-	32.7	V
Mixer/oscill	ator part; V _{CC} = 5 V; T _{amb} = 2	5 °C; measurements related to the	measure	ement cir	cuit (see	Fig.19)
VHF MIXER (INCLUDING IF PREAMPLIFIER)				· · · · · · · · · · · · · · · · · · ·	
f _{RF(o)}	RF operational frequency		40		800	MHz
f _{RF}	RF frequency	note 1	55.25	_	361.25	MHz
G _v	voltage gain	f _{RF} = 57.5 MHz; see Fig.12	17.5	20	22.5	dB
•		f _{RF} = 363.5 MHz; see Fig.12	17.5	20	22.5	dB
NF	noise figure	f _{RF} = 50 MHz; see Figs 13 and 14	_	7.5	10	dB
		f _{RF} = 150 MHz; see Figs 13 and 14	_	7.5	10	dB
		f _{RF} = 300 MHz; see Fig.14	_	7.5	10	dB

TDA6502; TDA6502A; TDA6503; TDA6503A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _o	output voltage (causing 1%	f _{RF} = 55.25 MHz; see Fig.15	107	110	-	dΒμV
	cross modulation in channel)	f _{RF} = 361.25 MHz; see Fig.15	107	110	_	dΒμV
Vi	input voltage (causing pulling-in channel at 750 Hz)	f _{RF} = 361.25 MHz; note 2	_	83	_	dBμV
gos	optimum source	f _{RF} = 50 MHz	_	0.7	_	mS
	conductance for noise figure	f _{RF} = 150 MHz	_	0.9	_	mS
		f _{RF} = 300 MHz	_	1.5	_	mS
gi	input conductance	f _{RF} = 55.25 MHz; see Fig.7	_	0.3	_	mS
		f _{RF} = 361.25 MHz; see Fig.7	_	0.4	_	mS
C _i	input capacitance	f _{RF} = 57.5 to 357.5 MHz; see Fig.7	_	1.35	_	pF
VHF oscill	ATOR					
f _{OSC(o)}	oscillator operational frequency		60		600	MHz
f _{OSC}	oscillator frequency	note 3	101	_	407	MHz
$\Delta f_{OSC(V)}$	oscillator frequency variation	ΔV_{CC} = 5%; note 4	_	60	_	kHz
	with supply voltage	ΔV_{CC} = 10%; note 4	_	110	_	kHz
$\Delta f_{OSC(T)}$	oscillator frequency variation with temperature	$\Delta T = 25$ °C; with compensation; note 5	_	1600	_	kHz
$\Delta f_{OSC(t)}$	oscillator frequency drift	5 s to 15 min after switch-on; note 6	_	400	_	kHz
$\Phi_{\sf OSC}$	phase noise, carrier-to-noise sideband	±100 kHz frequency offset; worst case in the frequency range	_	105	_	dBc/Hz
RSC	ripple susceptibility of V _{CC} (peak-to-peak value)	V _{CC} = 5 V; worst case in the frequency range; ripple frequency 500 kHz; note 7	15	30	-	mV
UHF MIXER	(INCLUDING IF PREAMPLIFIER)				•	
f _{RF(o)}	RF operational frequency		200		900	MHz
f _{RF}	RF frequency	note 1	367.25	_	801.25	MHz
G _v	voltage gain	f _{RF} = 369.5 MHz; see Fig.16	29	32	35	dB
		f _{RF} = 803.5 MHz; see Fig.16	29	32	35	dB
NF	noise figure (not corrected	f _{RF} = 369.5 MHz; see Fig.17	_	7	9	dB
	for image)	f _{RF} = 803.5 MHz; see Fig.17	_	7	9	dB
Vo	output voltage (causing 1%	f _{RF} = 367.25 MHz; see Fig.18	107	110	_	dΒμV
	cross modulation in channel)	f _{RF} = 801.25 MHz; see Fig.18	107	110	_	dΒμV
Vi	input voltage (causing pulling in channel at 750 Hz)	f _{RF} = 801.25 MHz; note 2	_	85	_	dBμV

TDA6502; TDA6502A; TDA6503A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Z _i	input impedance ($R_S + jL_S\omega$)	R _S at f _{RF} = 367.25 MHz; see Fig.8	_	26	_	Ω
		R _S at f _{RF} = 801.25 MHz; see Fig.8	_	28	_	Ω
		L _S at f _{RF} = 367.25 MHz; see Fig.8	_	8.5	_	nH
		L _S at f _{RF} = 801.25 MHz; see Fig.8	_	8	_	nH
UHF oscill	ATOR					
f _{OSC(o)}	oscillator operational frequency		300		1000	MHz
fosc	oscillator frequency	note 3	413	_	847	MHz
$\Delta f_{OSC(V)}$	oscillator frequency variation	ΔV_{CC} = 5%; note 4	_	35	_	kHz
	with supply voltage	ΔV_{CC} = 10%; note 4	_	100	_	kHz
$\Delta f_{OSC(T)}$	oscillator frequency variation with temperature	$\Delta T = 25$ °C; with compensation; note 5	-	500	_	kHz
$\Delta f_{OSC(t)}$	oscillator frequency drift	5 s to 15 min after switching on; note 6	_	120	_	kHz
$\Phi_{\sf OSC}$	phase noise, carrier-to-noise sideband	±100 kHz frequency offset; worst case in the frequency range	_	105	_	dBc/Hz
RSC	ripple susceptibility of V _{CC} (peak-to-peak value)	V _{CC} = 5 V; worst case in the frequency range; ripple frequency 500 kHz; note 7	15	30	_	mV
IF PREAMPLI	FIER		•	•	•	•
IF	IF operational frequency		30		60	MHz
S ₂₂	output reflection coefficient	magnitude; see Fig.9	_	-12.8	_	dB
		phase; see Fig.9	_	0.2	_	degree
Z _o	output impedance	R _S at 43.5 MHz; see Fig.9	_	80	_	Ω
	$(R_S + jL_S\omega)$	L _S at 43.5 MHz; see Fig.9	_	0.5	_	nH
REJECTION A	AT THE IF OUTPUT					
INT _{div}	level of divider interferences in the IF signal	worst case; note 8	_	16	20	dBμV
INT _{xtal}	crystal oscillator interferences rejection	V_{IF} = 100 dB μ V; worst case in the frequency range; note 9	60	-	_	dBc
INT _{ref}	reference frequency rejection	V_{IF} = 100 dB μ V; worst case in the frequency range; f _{REF} = 62.5 kHz; note 10	60	-	-	dBc
INT _{ch6}	channel 6 beat	$V_{RF(pix)} = V_{RF(snd)} = 80 \text{ dB}\mu\text{V};$ note 11	tbf	54	-	dBc
INT _{chA-5}	channel A-5 beat	$V_{RF(pix)} = 80 \text{ dB}\mu\text{V}$; note 12	tbf	60	_	dBc

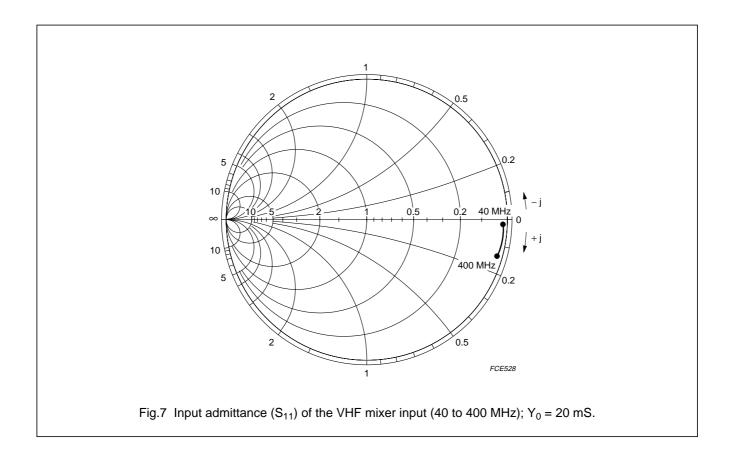
Notes

- 1. The RF frequency range is defined by the oscillator frequency range and the IF frequency.
- 2. This is the level of the RF signal (100% amplitude modulated with 11.89 kHz) that causes a 750 Hz frequency deviation on the oscillator signal; it produces sidebands 30 dB below the level of the oscillator signal.
- 3. Limits are related to the tank circuits used in Fig.19; frequency bands may be adjusted by the choice of external components.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

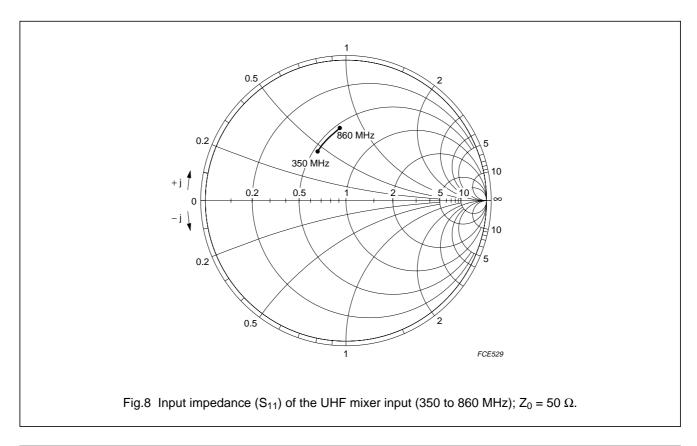
TDA6502; TDA6502A; TDA6503A

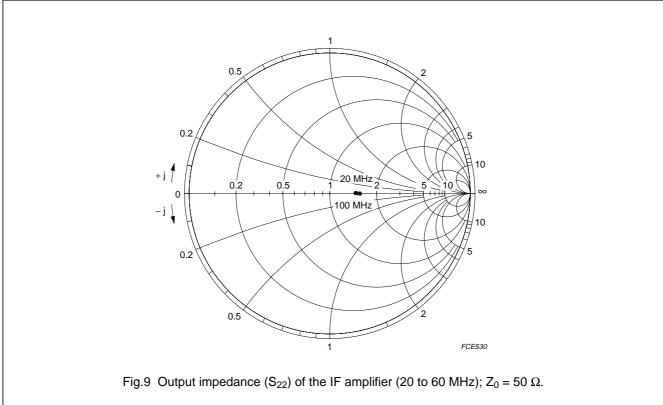
- 4. The frequency shift is defined as a change in oscillator frequency when the supply voltage varies from $V_{CC} = 5$ to 4.75 V (4.5 V) or from $V_{CC} = 5$ to 5.25 V (5.5 V). The oscillator is free running during this measurement.
- The frequency drift is defined as a change in oscillator frequency when the ambient temperature varies from T_{amb} = 25 to 50 °C or from T_{amb} = 25 to 0 °C. The oscillator is free running during this measurement.
- 6. Switch-on drift is defined as the change in oscillator frequency between 5 s and 15 min after switch-on. The oscillator is free running during this measurement.
- 7. The ripple susceptibility is measured for a 500 kHz ripple at the IF output using the measurement circuit of Fig.19; the level of the ripple signal is increased until a difference of 53.5 dB occurs between the IF carrier fixed at 100 dB μ V and the sideband components.
- 8. This is the level of divider interferences close to the IF frequency. For example channel C: $f_{OSC} = 179$ MHz, $\frac{1}{4} f_{OSC} = 44.75$ MHz. The VHFIN input must be left open (i.e. not connected to any load or cable); The UHFIN1 and UHFIN2 inputs are connected to a hybrid.
- Crystal oscillator interference means the 4 MHz sidebands caused by the crystal oscillator. The rejection has to be greater than 60 dB for an IF output signal of 100 dBμV.
- 10. The reference frequency rejection is the level of reference frequency sidebands related to the sound sub-carrier.
- 11. Channel 6 beat is the interfering product of f_{RF(pix)} + f_{RF(snd)} f_{OSC} of channel 6 at 42 MHz.
- 12. Channel A-5 beat is the interfering product of $f_{RF(pix)}$, f_{IF} and f_{OSC} of channel A-5: f_{beat} = 45.5 MHz. The possible mechanisms are: $f_{OSC} 2 \times f_{IF}$ or $2 \times f_{RF(pix)} f_{OSC}$. For the measurement: V_{RF} = 80 dB μ V.



5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A

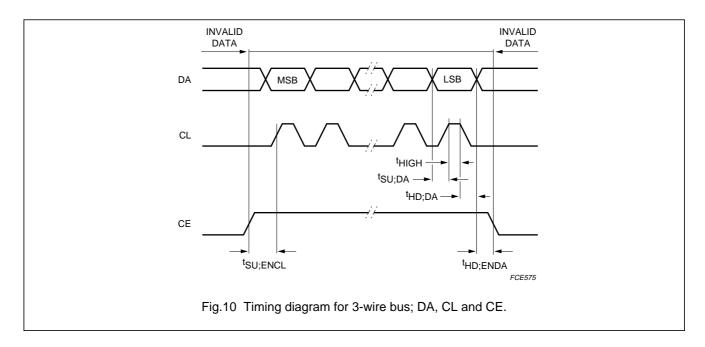


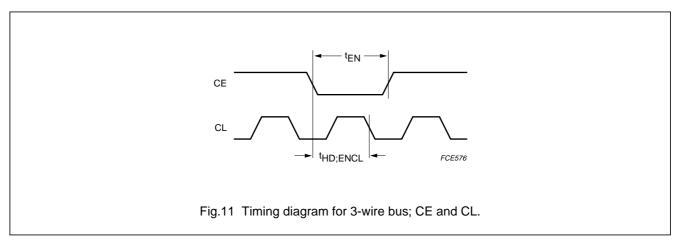


TDA6502; TDA6502A; TDA6503; TDA6503A

12 TIMING CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	UNIT
3-wire bus tim	ing			
t _{HIGH}	clock HIGH time	see Fig.10	2	μs
t _{SU;DA}	data set-up time	see Fig.10	2	μs
t _{HD;DA}	data hold time	see Fig.10	2	μs
t _{SU;ENCL}	enable-to-clock set-up time	see Fig.10	10	μs
t _{HD;ENDA}	enable-to-data hold time	see Fig.10	2	μs
t _{EN}	enable time between two transmissions	see Fig.11	10	μs
t _{HD;ENCL}	enable-to-clock active edge hold time	see Fig.11	6	μs



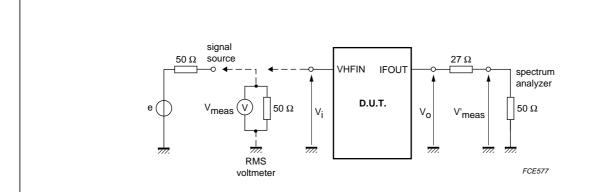


5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A

13 TEST AND APPLICATION INFORMATION

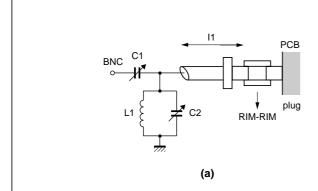
13.1 **Test circuits**

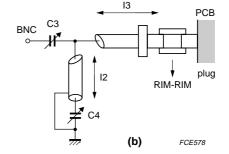


 $Z_{i} >> 50~\Omega \Rightarrow V_{i} = 2 \times V_{meas} = 80~dB\mu V$ $V_i = V_{meas} + 6 dB = 80 dB\mu V$ $V_0 = V'_{meas} \times \frac{50 + 27}{50}$

 $G_v = 20 \log \frac{V_0}{V}$

Fig.12 Gain measurement in VHF band.





(a) For $f_{RF} = 50 \text{ MHz}$:

mixer A frequency response measured = 57 MHz, loss = 0 dB image suppression = 16 dB

C1 = 9 pF

C2 = 15 pF

L1 = 7 turns (\varnothing 5.5 mm, wire \varnothing = 0.5 mm)

I1 = semi rigid cable (RIM) of 5 cm long (semi rigid cable (RIM); 33 dB/100 m; 50 Ω ; 96 pF/m).

(b) For $f_{RF} = 150 \text{ MHz}$:

mixer A frequency response measured = 150.3 MHz, loss = 1.3 dB image suppression = 13 dB

C3 = 5 pF

C4 = 25 pF

I2 = semi rigid cable (RIM): 30 cm long

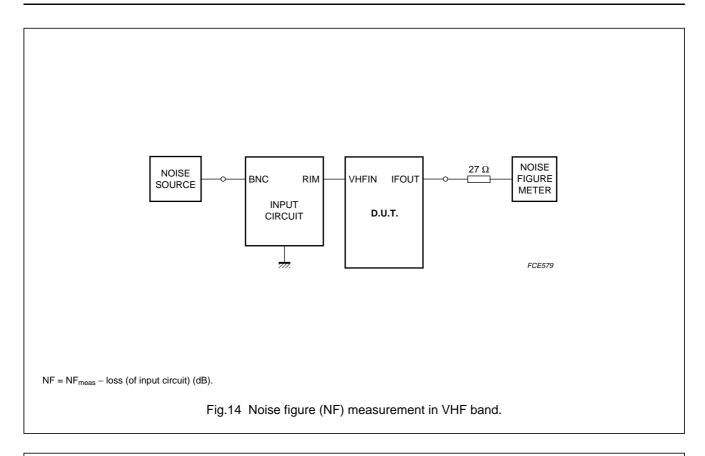
I3 = semi rigid cable (RIM) of 5 cm long (semi rigid cable (RIM); 33 dB/100 m; 50 Ω ; 96 pF/m).

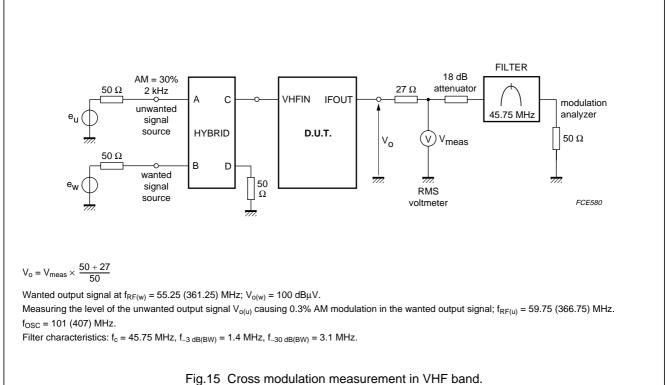
Fig.13 Input circuit for optimum noise figure in VHF band.

2000 Mar 16 24

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

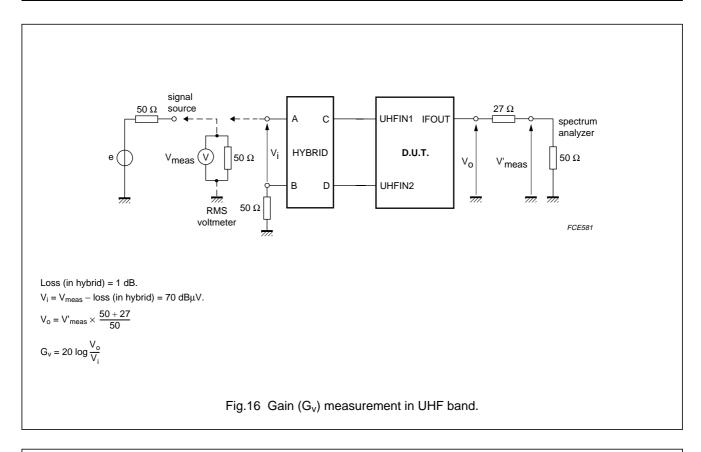
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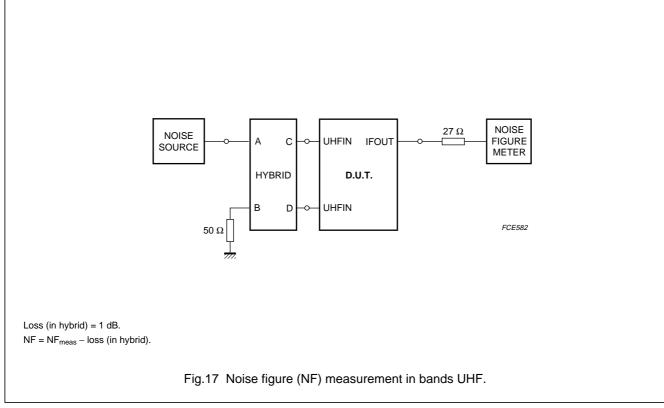




5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

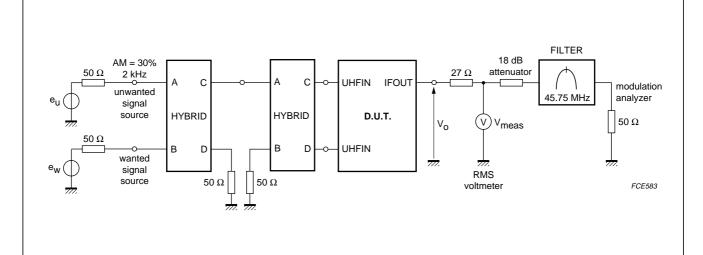
TDA6502; TDA6502A; TDA6503; TDA6503A





5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503



 $V_0 = V_{meas} \times \frac{50 + 27}{50}$

Wanted output signal at $f_{RF(w)}$ = 367.25 (801.25) MHz; $V_{o(w)}$ = 100 dB μ V.

Measuring the level of the unwanted output signal $V_{o(u)}$ causing 0.3% AM modulation in the wanted output signal; $f_{RF(u)} = 371.25$ (805.75) MHz. $f_{OSC} = 413$ (847) MHz.

Filter characteristics: f_c = 45.75 MHz, $f_{-3~dB(BW)}$ = 1.4 MHz, $f_{-30~dB(BW)}$ = 3.1 MHz.

Fig.18 Cross modulation measurement in UHF band.

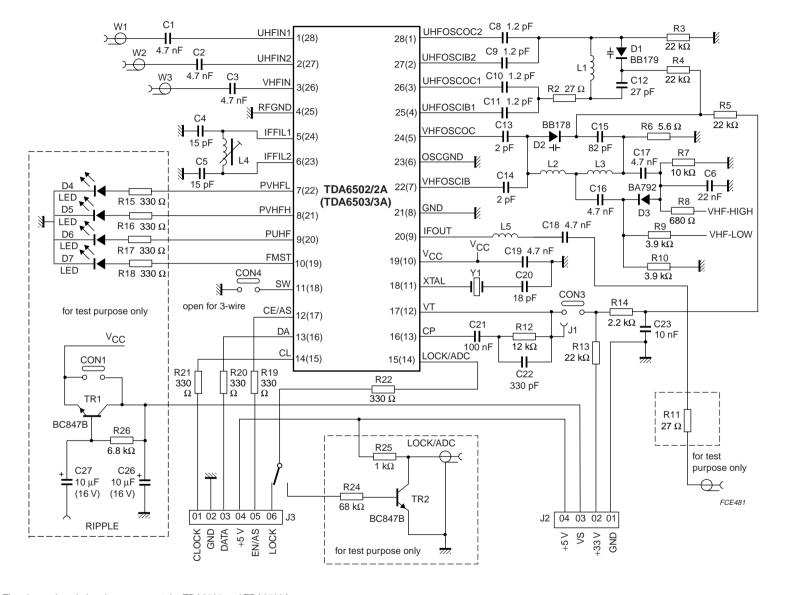
28

Philips Semiconductors

13.2

Measurement circuit

TDA6502; TDA6502A; TDA6503A



The pin numbers in brackets represent the TDA6503 and TDA6503A.

Fig.19 Measurement circuit.

TDA6502; TDA6502A; TDA6503; TDA6503A

Table 13 Capacitors (all SMD and NP0)

COMPONENT	VALUE
C1	4.7 nF
C2	4.7 nF
C3	4.7 nF
C4	15 pF
C5	15 pF
C6	22 nF
C8	1.2 pF (N750)
C9	1.2 pF (N750)
C10	1.2 pF(N750)
C11	1.2 pF (N750)
C12	27 pF (N750)
C13	2 pF (N750)
C14	2 pF (N750)
C15	82 pF (N750)
C16	4.7 nF
C17	4.7 nF
C18	4.7 nF
C19	4.7 nF
C20	18 pF
C21	100 nF
C22	330 pF
C23	10 nF
C26	10 μF (16 V, electrolytic)
C27	10 μF (16 V, electrolytic)

Table 14 Resistors (all SMD)

COMPONENT	VALUE
R2	27 Ω
R3	22 kΩ
R4	22 kΩ
R5	22 kΩ
R6	5.6 Ω
R7	10 kΩ
R8	680 Ω
R9	3.9 kΩ
R10	3.9 kΩ
R11	27 Ω
R12	12 kΩ
R13	22 kΩ
R14	2.2 kΩ

COMPONENT	VALUE
R15	330 Ω
R16	330 Ω
R17	330 Ω
R18	330 Ω
R19	330 Ω
R20	330 Ω
R21	330 Ω
R22	330 Ω
R24	68 kΩ
R25	1 kΩ
R26	6.8 kΩ

Table 15 Diodes and ICs

COMPONENT	VALUE
D1	BB179
D2	BB178
D3	BA792
IC	TDA6502; TDA6502A TDA6503; TDA6503A

Table 16 Coils (note 1)

COMPONENT	VALUE
L1	1.5 turns; diameter 1.5 mm
L2	2.5 turns; diameter 2.5 mm
L3	7.5 turns; diameter 3.0 mm
L5	2.5 turns; diameter 2.5 mm

Note

1. Wire size is 0.4 mm.

Table 17 Transformer (note 1)

COMPONENT	VALUE
L4	2 x 5 turns

Note

1. Coil type: TOKO 7kN; material: 113 kN; screw core: 03-0093; pot core: 04-0026.

Table 18 Crystal

COMPONENT	VALUE
Y1	4 MHz

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503A

Table 19 Transistors

COMPONENT	VALUE
TR1	BC847B
TR2	BC847B

13.3 Tuning amplifier

The tuning amplifier is capable of driving the varicap voltage without an external transistor. The tuning voltage output must be connected to an external load of 27 k Ω which is connected to the tuning voltage supply rail. The loop filter design depends on the oscillator characteristics and the selected reference frequency.

13.4 Crystal oscillator

The crystal oscillator uses a 4 MHz crystal connected in series with an 18 pF capacitor thereby operating in the series resonance mode. Connecting the crystal to the ground is preferred, but it can also be connected to the supply voltage.

13.5 Examples of I²C-bus data format sequences for TDA6502 and TDA6503

Tables 20 to 24 show the various write sequences where:

S = START bit

A = acknowledge bit

P = STOP bit.

Conditions:

 $f_{xtal} = 4 \text{ MHz}$

N = 1600

 $f_{osc} = 100 \text{ MHz}$

 $f_{\text{step}} = 62.5 \text{ kHz}$

Port register VHFL is 'on' to switch-on band VHF low Port register FMST is 'on' to switch-on an FM sound trap $I_{CP}=280\ \mu A.$

13.5.1 WRITE SEQUENCES TO REGISTER C2

Table 20 Complete sequence with first the divider bytes (first data bit = 0)

START	ADDRESS BYTE	ACK	DIVIDER BYTE 1	ACK	DIVIDER BYTE 2	ACK	CONTROL BYTE	ACK	BAND- SWITCH BYTE	ACK	STOP
S	C2	Α	06	Α	40	Α	CE	Α	09	Α	Р

Table 21 Complete sequence with first the control and band-switch bytes (first data bit = 1)

START	ADDRESS BYTE	ACK	CONTROL BYTE	ACK	BAND- SWITCH BYTE	ACK	DIVIDER BYTE 1	ACK	DIVIDER BYTE 2	ACK	STOP
S	C2	Α	CE	Α	09	Α	06	Α	40	Α	Р

Table 22 Sequence with divider bytes only (first data bit = 0)

START	ADDRESS BYTE	ACK	DIVIDER BYTE 1	ACK	DIVIDER BYTE 2	ACK	STOP
S	C2	Α	06	Α	40	Α	Р

Table 23 Sequence with control and band-switch bytes only (first data bit = 1)

START	ADDRESS BYTE	ACK	CONTROL BYTE	ACK	BAND-SWITCH BYTE	ACK	STOP
S	C2	Α	CE	Α	09	Α	Р

Table 24 Sequence with control byte only (first data bit = 1)

START	ADDRESS BYTE	ACK	CONTROL BYTE	ACK	STOP
S	C2	Α	CE	Α	Р

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503

13.5.2 READ SEQUENCES FROM REGISTER C3

Tables 25 and 26 show the various read sequences where:

S = START bit

A = acknowledge bit

XX = read status byte

X = no acknowledge from the master means end of sequence

P = STOP bit

Table 25 One status byte acquisition

START	ADDRESS BYTE	ACK	STATUS BYTE	ACK	STOP
S	C3	Α	XX	Х	Р

Table 26 Two status bytes acquisition

START	ADDRESS BYTE	ACK	STATUS BYTE	ACK	STATUS BYTE	ACK	STOP
S	C3	Α	XX	Α	XX	Х	Р

13.6 Examples of 3-wire bus data format sequences for TDA6502 and TDA6503

13.6.1 18-BIT SEQUENCE

Conditions:

 $f_{osc} = 800 \text{ MHz}$

Port register PUHF is 'on'.

Table 27 18-bit sequence

PUHF	FMST	PVHFH	PVHFL	N13	N12	N11	N10	N9	N8	N7	N6	N5	N4	N3	N2	N1	N0
1	0	0	0	1	1	1	0	0	1	0	0	0	0	0	0	0	0

The reference divider is automatically set to 64 assuming that bit RSB has been set to logic 1 at power-on. If bit RSB has been set to logic 0, in a previous 27-bit sequence, the reference divider will still be set at 80. In this event, the 18-bit sequence has to be adapted to the 80 divider ratio.

13.6.2 19-BIT SEQUENCE

Conditions:

 $f_{osc} = 650 \text{ MHz}$

Port register PUHF is 'on'.

Table 28 19-bit sequence

PUHF	FMST	PVHFH	PVHFL	N14	N13	N12	N11	N10	N9	N8	N7	N6	N5	N4	N3	N2	N1	N0
1	0	0	0	1	0	1	0	0	0	1	0	1	0	0	0	0	0	0

The reference divider is automatically set to 128 assuming that bit RSB has been set to logic 1 at power-on. If bit RSB has been set to logic 0 in a previous 27-bit sequence, the reference divider will still be set at 80. In this event, the 19-bit sequence has to be adapted to the 80 divider ratio.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503

13.6.3 27-BIT SEQUENCE

Conditions:

 $f_{osc} = 750 \text{ MHz}$

Port register PUHF is 'on'

Reference divider is set at 80

 $I_{CP} = 60 \,\mu\text{A}$

No test function.

Table 29 27-bit sequence

DC.	PORT BITS 1 0 0 0					FR	EQ	JEN	CY	DAT	A BI	TS							CON	NTRO	DL D	ATA BI	TS	
	KI BIIS	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	X	СР	T2	T1	T0	RSA	RSB	os
1	0 0 0	0	1	1	1	0	1	0	1	0	0	1	1	0	0	0	1	0	0	0	1	0	0	0

To change the oscillator frequency to 600 MHz in 50 kHz steps a 19-bit sequence or an 18-bit sequence can be used. The charge pump current remains at $60 \, \mu A$.

Table 30 Changing frequency with a 19-bit sequence

PORT BITS FREQUENCY DATA BITS 14 13 12 11 10 9 8 7 6 5											ITS							
	PUKI	ыз		14	1 7 3		11	10	9	8	7	6	5	4	3	2	1	0
1	0	0	0	0	1	0	1	1	1	0	1	1	1	0	0	0	0	0

Table 31 Changing frequency with an 18-bit sequence

	DODI	ріте							FREQ	UENC	Y DATA	BITS					
	PORT BITS				12	11	10	9	8	7	6	5	4	3	2	1	0
1	0	0	0	1	0	1	1	1	0	1	1	1	0	0	0	0	0

TDA6502; TDA6502A; TDA6503; TDA6503A

14 INTERNAL PIN CONFIGURATION

SYMBOL	P	IN		LTAGE VALUE) ⁽²⁾	EQUIVALENT CIRCUIT(1)
STMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	VHF	UHF	EQUIVALENT CIRCUIT
UHFIN1	1	28	_	1.0 V	
UHFIN2	2	27	-	1.0 V	(28) (27) FCE584
VHFIN	3	26	-	-	(26) FCE585
RFGND	4	25	0.0 V	0.0 V	(25) FCE586
IFFIL1	5	24	3.6 V	3.6 V	(24) (5) (6)(23)
IFFIL2	6	23	3.6 V	3.6 V	FCES87
PVHFL	7	22	n.a. or 4.8 V	n.a.	<u> </u>
PVHFH	8	21	4.8 V or n.a.	n.a.	
PUHF	9	20	n.a.	4.8 V	
FMST	10	19	n.a. or 4.8 V	n.a. or 4.8 V	9 (20) (20) (20) (30) (10) (19) (19) (19)

TDA6502; TDA6502A; TDA6503; TDA6503A

CVMDOL	P	IN		LTAGE E VALUE) ⁽²⁾	EQUIVAL FAIT CIDOLUT(1)
SYMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	VHF	UHF	EQUIVALENT CIRCUIT ⁽¹⁾
SW	11	18	5.0 V	5.0 V	(11) (18) FCE189
CE/AS	12	17	1.25 V	1.25 V	(12) (17) FCE191
DA	13	16	-	-	(13) (16) FCE190
CL	14	15	-	-	(14) (15) FCE192
LOCK/ADC	15	14	4.6 V	4.6 V	(14) FCE193

TDA6502; TDA6502A; TDA6503; TDA6503A

SYMBOL	PI	IN		LTAGE VALUE) ⁽²⁾	EQUIVALENT CIRCUIT ⁽¹⁾
STMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	VHF	UHF	EQUIVALENT CIRCUIT
СР	16	13	1 V	1 V	16) (13) FCE194
VT	17	12	V _{VT}	V _{VT}	(12) FCE589
XTAL	18	11	2.6 V	2.6 V	18 (11) FCE590
V _{CC}	19	10	5.0 V	5.0 V	supply voltage
IFOUT	20	9	2.1 V	2.1 V	FCE591 (9)
GND	21	8	0.0 V	0.0 V	(21) (8) FCE592

TDA6502; TDA6502A; TDA6503; TDA6503A

SYMBOL	P	IN		LTAGE VALUE) ⁽²⁾	EQUIVALENT CIRCUIT ⁽¹⁾
STMBOL	TDA6502; TDA6502A	TDA6503; TDA6503A	VHF	UHF	EQUIVALENT CIRCUIT
OSCGND	23	6	0.0 V	0.0 V	(6) FCE593
VHFOSCIB	22	7	1.8 V	_	
VHFOSCOC	24	5	3.0 V	_	(7) FCE594
UHFOSCIB1	25	4	_	1.9 V	1 1
UHFOSCOC1	26	3	_	2.9 V	(2)
UHFOSCOC2	27	2	-	2.9 V	29 - 4 - 26
UHFOSCIB2	28	1	_	1.9 V	(4) (1) FCE595

Notes

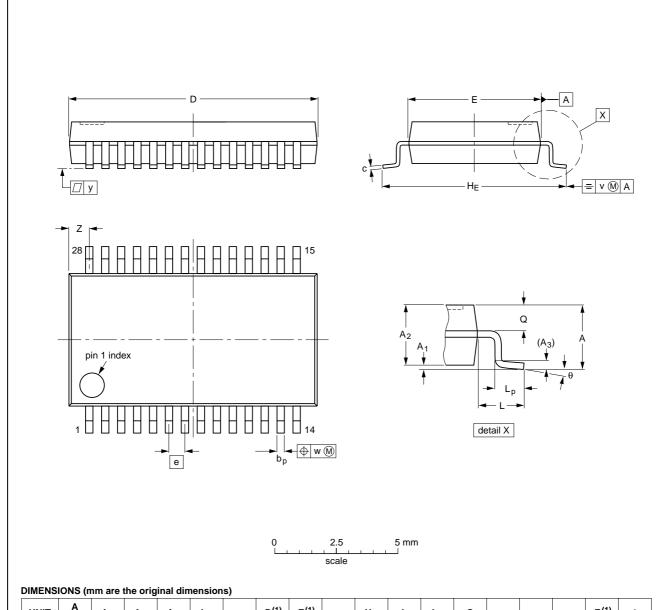
- 1. The pin numbers in parenthesis represent the TDA6503 and TDA6503A.
- 2. Measured in circuit of Fig.19.

TDA6502; TDA6502A; TDA6503; TDA6503A

15 PACKAGE OUTLINE

SSOP28: plastic shrink small outline package; 28 leads; body width 5.3 mm

SOT341-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	10.4 10.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.1 0.7	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

	OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE	
		IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
	SOT341-1		MO-150				95-02-04 99-12-27

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503A

16 SOLDERING

16.1 Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

16.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 230 °C.

16.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

16.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300~^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^{\circ}$ C.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503;

16.5 Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD		
PACKAGE	WAVE	REFLOW ⁽¹⁾	
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable	
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable(2)	suitable	
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable	
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

5 V mixers/oscillators and synthesizers for cable TV and VCR 2-band tuners

TDA6502; TDA6502A; TDA6503; TDA6503

17 DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

18 LIFE SUPPORT APPLICATIONS

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TDA6502; TDA6502A; TDA6503; TDA6503A

NOTES

TDA6502; TDA6502A; TDA6503; TDA6503A

NOTES

TDA6502; TDA6502A; TDA6503; TDA6503A

NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 3 Figtree Drive, HOMEBUSH, NSW 2140, Tel. +61 2 9704 8141, Fax. +61 2 9704 8139 Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 1 60 101 1248. Fax. +43 1 60 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,

220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

Belgium: see The Netherlands Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,

51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 68 9211, Fax. +359 2 68 9102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,

Tel. +1 800 234 7381, Fax. +1 800 943 0087

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,

72 Tat Chee Avenue, Kowloon Tong, HONG KONG, Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America Czech Republic: see Austria

Denmark: Sydhavnsgade 23, 1780 COPENHAGEN V,

Tel. +45 33 29 3333, Fax. +45 33 29 3905 Finland: Sinikalliontie 3, FIN-02630 ESPOO, Tel. +358 9 615 800, Fax. +358 9 6158 0920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,

Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,

Tel. +49 40 2353 60, Fax. +49 40 2353 6300

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor, 254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,

Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: PT Philips Development Corporation, Semiconductors Division,

Gedung Philips, Jl. Buncit Raya Kav. 99-100, JAKARTA 12510, Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI),

Tel. +39 039 203 6838. Fax +39 039 203 6800

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL, Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,

Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,

Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,

Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,

Tel. +64 9 849 4160, Fax. +64 9 849 7811 Norway: Box 1, Manglerud 0612, OSLO, Tel. +47 22 74 8000, Fax. +47 22 74 8341

Pakistan: see Singapore

Philippines: Philips Semiconductors Philippines Inc., 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Al.Jerozolimskie 195 B, 02-222 WARSAW, Tel. +48 22 5710 000, Fax. +48 22 5710 001

Portugal: see Spain

Russia: Philips Russia, UI. Usatcheva 35A, 119048 MOSCOW,

Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762,

Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,

2092 JOHANNESBURG, P.O. Box 58088 Newville 2114,

Tel. +27 11 471 5401, Fax. +27 11 471 5398 South America: Al. Vicente Pinzon, 173, 6th floor, 04547-130 SÃO PAULO, SP. Brazil.

Tel. +55 11 821 2333. Fax. +55 11 821 2382 Spain: Balmes 22, 08007 BARCELONA Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,

Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH, Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1, TAIPEI, Taiwan Tel. +886 2 2134 2886, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd. 209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,

Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye,

ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,

252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461 United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes,

MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421 United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,

Tel. +1 800 234 7381, Fax. +1 800 943 0087

Uruguay: see South America Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,

Tel. +381 11 3341 299, Fax.+381 11 3342 553

For all other countries apply to: Philips Semiconductors, International Marketing & Sales Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

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